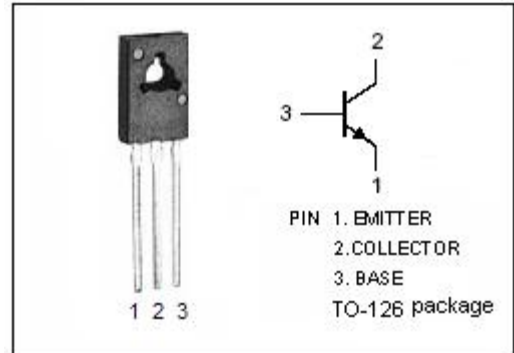


**isc Silicon NPN Power Transistor**
**2SC1953**
**DESCRIPTION**

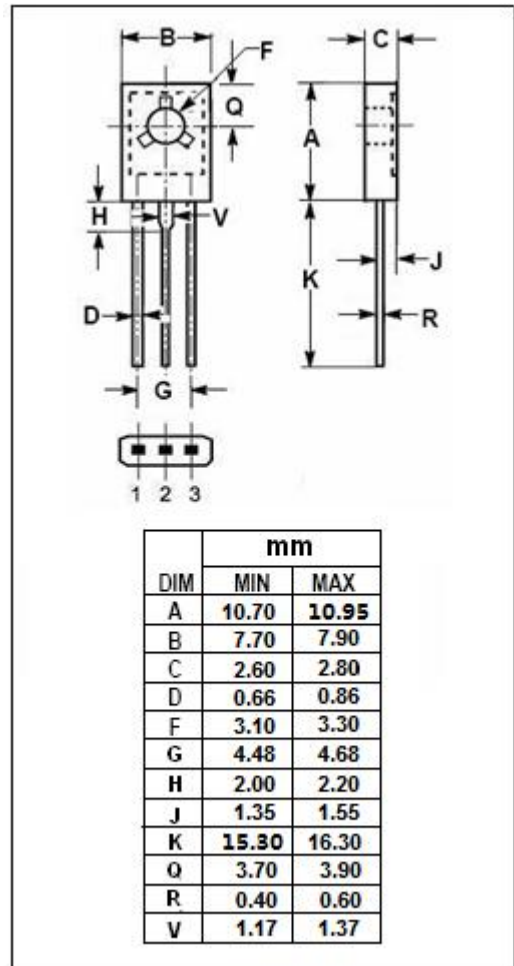
- High Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 150V(\text{Min})$
- Good Linearity of  $h_{FE}$
- Complement to Type 2SA914
- Minimum Lot-to-Lot variations for robust device performance and reliable operation


**APPLICATIONS**

- Designed for low-frequency power pre-amplification, which is optimum for the pre-driver stage of a 60 W to 100 W output amplifier.

**ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	150	V
$V_{CEO}$	Collector-Emitter Voltage	150	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current-Continuous	50	mA
$I_{CP}$	Collector Current-Peak	100	mA
$P_C$	Collector Power Dissipation @ $T_a = 25^\circ\text{C}$	1.2	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



**isc Silicon NPN Power Transistor**
**2SC1953**
**ELECTRICAL CHARACTERISTICS**

 T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 0.1mA ; I <sub>B</sub> = 0	150			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 10 μ A ; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 30mA; I <sub>B</sub> = 3mA			1	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 100V; I <sub>E</sub> = 0			1	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4V; I <sub>C</sub> = 0			1	μ A
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 10mA ; V <sub>CE</sub> = 5V	130		330	
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 10mA; V <sub>CE</sub> = 10V, f <sub>test</sub> = 200MHz	70			MHz
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V, f <sub>test</sub> = 1MHz			3	pF

**◆ h<sub>FE</sub> Classifications**

Q	R
130-220	185-330

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